

2N3019S

2N3019S Information



Part Number	2N3019S
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN 80V 1A TO-39
Package	TO-205AD, TO-39-3 Metal Can
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



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For Reference Only

Certified Quality

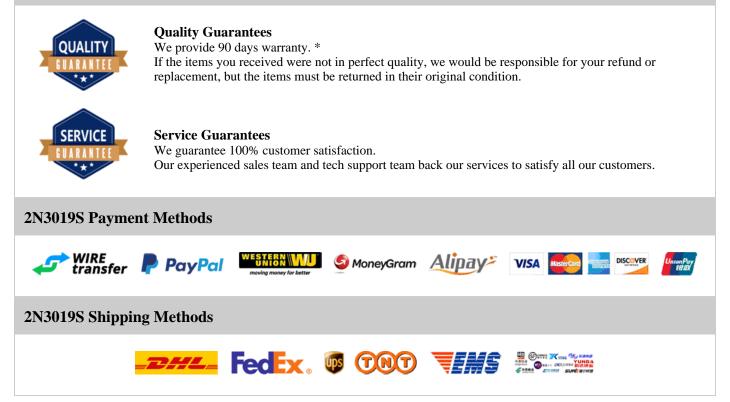
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2N3019S Specifications

Manufacturer Part Number	2N3019S
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-205AD, TO-39-3 Metal Can
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	80V
Vce Saturation (Max) @ Ib, Ic	500mV @ 50mA, 500mA
Current - Collector Cutoff (Max)	10nA
DC Current Gain (hFE) (Min) @ Ic, Vce	50 @ 500mA, 10V
Power - Max	800mW
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-205AD, TO-39-3 Metal Can
Supplier Device Package	TO-39
	Report errors?

2N3019S Guarantees



If you have any question about 2N3019S, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com